

Transient Voltage Suppressors SMCJ5.0(C)A - SMCJ170(C)A

Features

- · Glass passivated junction.
- 1500 W Peak Pulse Power capability on 10/1000 μs waveform.
- · Excellent clamping capability.
- Low incremental surge resistance.
- Fast response time; typically less than 1.0 ps from 0 volts to BV for unidirectional and 5.0 ns for bidirectional.
- Typical I_p less than 1.0 μA above 10V.
- UL certified, UL #E210467.



SMC/DO-214AB

COLOR BAND DENOTES CATHODE
ON UNIDIRECTIONAL DEVICES ONLY.
NO COLOR BAND ON BIDIRECTIONAL
DEVICES.

DEVICES FOR BIPOLAR APPLICATIONS

- Bidirectional types use CA suffix.

- Electrical Characteristics apply in both directions.

1500 Watt Transient Voltage Suppressors

Absolute Maximum Ratings*

T_A = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
P _{PPM}	Peak Pulse Power Dissipation on 10/1000 μs waveform	1500	W
I _{PPM}	Peak Pulse Current on 10/1000 μs waveform	see table	А
I _{FSM}	Non-repetitive Peak Forward Surge Current superimposed on rated load (JEDEC method) (Note 1)	200	А
T _{stg}	Storage Temperature Range	-55 to +150	°C
T _J	Operating Junction Temperature	+ 150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Note 1: Measured on 8.3 ms single half-sine wave or equivalent square wave; Duty cycle = 4 pulses per minute maximum.

Transient Voltage Suppressors (continued)

Electrical Characteristics

Uni-directional Bi-directional (C) Device	Part Marking*	Reverse Stand-off Voltage V _{RWM} (V)	f Voltage V _{BR} (V)		Test Current I₁ (mA)	Clamping Voltage @I _{PPM} V _C (V)	Peak Pulse Current I _{PPM} (A)	Reverse Leakage @ V _{RWM} I _R (uA)**
		VRWM(V)	min	max		VC(V)		IR (UA)
SMCJ5.0(C)A	GDE	5.0	6.40	7.0	10	9.2	163.0	1000
SMCJ6.0(C)A	GDG	6.0	6.67	7.37	10	10.3	145.6	1000
SMCJ6.5(C)A	GDK(BDK)	6.5	7.22	7.98	10	11.2	133.9	500
SMCJ7.0(C)A	GDM	7.0	7.78	8.60	10	12.0	125.0	200
SMCJ7.5(C)A	GDP(BDP)	7.5	8.33	9.21	1	12.9	116.3	100
SMCJ8.0(C)A	GDR(BDR)	8.0	8.89	9.83	1	13.6	110.3	50
SMCJ8.5(C)A	GDT(BDT)	8.5	9.44	10.4	1	14.4	104.2	20
SMCJ9.0(C)A	GDV(BDV)	9.0	10.0	11.1	1	15.4	97.4	10
SMCJ10(C)A	GDX(BDX)	10	11.1	12.3	1	17.0	88.2	5
SMCJ11(C)A	GDZ	11	12.2	13.5	1	18.2	82.4	5
SMCJ12(C)A	GEE(BEE)	12	13.3	14.7	1	19.9	75.3	5
SMCJ13(C)A	GÈG	13	14.4	15.9	1	21.5	69.8	5
SMCJ14(C)A	GEK(BEK)	14	15.6	17.2	1	23.2	64.7	5
SMCJ15(C)A	GEM(BEM)	15	16.7	18.5	1	24.4	61.5	5
SMCJ16(C)A	GÈP	16	17.8	19.7	1	26.0	57.7	5
SMCJ17(C)A	GER	17	18.9	20.9	1	27.6	54.3	5
SMCJ18(C)A	GET(BET)	18	20.0	22.1	1	29.2	51.4	5
SMCJ20(C)A	GEV(BEV)	20	22.2	24.5	1	32.4	46.3	5
SMCJ22(C)A	GEX(BEX)	22	24.4	26.9	1	35.5	42.3	5
SMCJ24(C)A	GEZ(BEZ)	24	26.7	29.5	1	38.9	38.6	5
SMCJ26(C)A	GFE(BFE)	26	28.9	31.9	1	42.1	35.6	5
SMCJ28(C)A	GFG(BFG)	28	31.1	34.4	1	45.4	33.0	5
SMCJ30(C)A	GFK(BFK)	30	33.3	36.8	1	48.4	31.0	5
SMCJ33(C)A	GFM(BFM)	33	36.7	40.6	1	53.3	28.1	5
SMCJ36(C)A	GFP(BFP)	36	40.0	44.2	1	58.1	25.8	5
SMCJ40(C)A	GFR(BFR)	40	44.4	49.1	1	64.5	23.3	5
SMCJ43(C)A	GFT(BFT)	43	47.8	52.8	1	69.4	21.6	5
SMCJ45(C)A	GFV	45	50.0	55.3	1	72.7	20.6	5
SMCJ48(C)A	GFX	48	53.3	58.9	1	77.4	19.4	5
SMCJ51(C)A	GFZ	51	56.7	52.7	1	82.4	18.2	5
SMCJ54(C)A	GGE	54	60.0	66.3	1	87.1	17.2	5
SMCJ58(C)A	GGG	58	64.4	71.2	1	93.6	16.0	5
SMCJ60(C)A	GGK	60	66.7	73.7	1	96.8	15.5	5
SMCJ64(C)A	GGM	64	71.1	78.6	1	103.0	14.6	5
SMCJ70(C)A	GGP	70	77.8	86.0	1	113.0	13.3	5
SMCJ75(C)A	GGR	75	83.3	92.1	1	121.0	12.4	5
SMCJ78(C)A	GGT	78	86.7	95.8	1	126.0	11.9	5
SMCJ85(C)A	GGV	85	94.4	104.0	1	137.0	10.9	5
SMCJ90(C)A	GGX	90	100.0	111.0	1	146.0	10.3	5
SMCJ100(C)A	GGZ	100	111.0	123.0	1	162.0	9.3	5
SMCJ110(C)A	GHE	110	122.0	135.0	1	177.0	8.5	5
SMCJ120(C)A	GHG	120	133.0	147.0	1	193.0	7.8	5
SMCJ130(C)A	GHK	130	144.0	159.0	1	209.0	7.2	5
SMCJ150(C)A	GHM	150	167.0	185.0	1	243.0	6.2	5
SMCJ160(C)A	GHP	160	178.0	197.0	1	259.0	5.8	5
SMCJ170(C)A	GHR	170	189.0	209.0	1	275.0	5.5	5

^{*} Color band denotes cathode on unidirectional devices only. No color band on bidirectional devices.

^{**} For bidirectional parts with $\rm V_{RWM}\!\!<\!\!10V,$ the $\rm I_{R}$ max limit is doubled.

Transient Voltage Suppressors

(continued)

Typical Characteristics

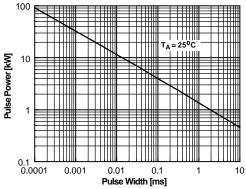


Figure 1. Peak Pulse Power Rating Curve

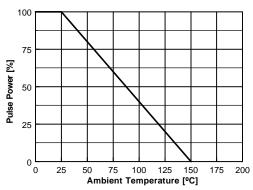


Figure 2. Pulse Derating Curve

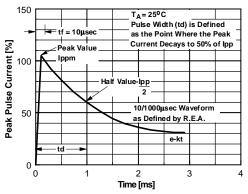


Figure 3. Pulse Waveform

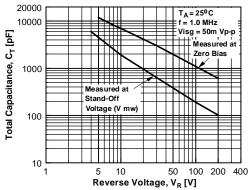


Figure 4. Total Capacitance

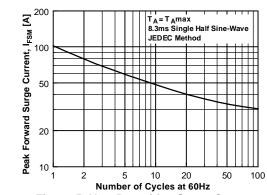


Figure 5. Non-Repetitive Surge Current

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